

JPW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of

Oh-Sung Song et al.

Group Art Unit 2812

Application No. 10/608,221

Examiner: TBA

Filed June 30, 2003

TITLE: METHOD FOR FABRICATING MOS SEMICONDUCTOR DEVICE HAVING SALICIDE  
REGION AND LID REGION

**REQUEST FOR CORRECTED FILING RECEIPT**

Commission for Patents  
P.O. Box 1450  
Alexandria VA 22313-1450

Sir:

Attached is a copy of the official filing receipt from the PTO in the above application  
for which issuance of a corrected filing receipt is respectfully requested.


Please correct the following data as follows:

Please change the Title to:

Method for fabricating mos semiconductor device having salicide region and **ldd**  
region

Respectfully submitted,

VOLENTINE FRANCOS & WHITT, PLLC

  
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June 9, 2005

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## UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE  
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APPL NO.	FILING OR 371 (c) DATE	ART UNIT	FIL FEE REC'D	ATTY. DOCKET NO	DRAWINGS	TOT CLMS	IND CLMS
10/608,221	06/30/2003	2812	834	SEC.559RE	7	17	4

20987  
VOLENTINE FRANCO, & WHITT PLLC  
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CONFIRMATION NO. 1783

FILING RECEIPT



00000016145512\*

VOLENTINE FRANCO  
P.L.L.C.  
JUN 2 2005  
**Received**

Date Mailed: 05/27/2005

Receipt is acknowledged of this reissue Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please mail to the Commissioner for Patents P.O. Box 1450 Alexandria Va 22313-1450. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

## Applicant(s)

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## Power of Attorney:

Adam Volentine--33289

## Domestic Priority data as claimed by applicant

This application is a REI of 09/161,979 09/29/1998 PAT 6,255,181

## Foreign Applications

REPUBLIC OF KOREA 97-50829 10/01/1997

If Required, Foreign Filing License Granted: 04/12/2005

The country code and number of your priority application, to be used for filing abroad under the Paris Convention, is **US10/608,221**

Projected Publication Date: None, application is not eligible for pre-grant publication

Non-Publication Request: No

Early Publication Request: No

**Title**

Method for fabricating mos semiconductor device having salicide region and ~~ld~~<sup>ldd</sup> region

**Preliminary Class**

438

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